Coexistence of Attractors in the Parallel Inductor-Capacitor-Memristor Circuit

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- Memristors.
- Parallel Inductor-Capacitor-Memristor Circuit.
- Bifurcation diagrams.
- Multiple attractors.
- Basins of attraction.
- Confirmation of the existence of multiple attractors.
- Conclusions.

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Memristors

- A classical memristor is a circuit element characterized by a nonlinear relation between charge and flux. Its resistance depends on the history of current flowing through the element or the voltage across the element.
- Memristors were theoretically introduced in 1971.
- Memristive behavior was recognized in a nano-scale double-layer ${\rm TiO}_2$ film in 2008.
- Memristors have received significant attention due to a number of possible applications including large-capacity nonvolatile memories and neuromorphic systems.
- It has been confirmed that memristors are useful for designing nonlinear oscillators.
- One of the simplest memristor circuits displaying complex behaviors is the parallel inductor-capacitor-memristor circuit.

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Current controlled memristor

• For the *ideal charge-controlled memristor* there exist a constitutive relation between the charge q and the magnetic flux φ in the form $\varphi = f_M(q)$. The relation between the voltage and the current is

$$u = R(q)i, \quad R(q) = rac{df_M(q)}{dq}$$

- The memristance R(q) is a function of the charge q.
- The memristor can be considered as the fourth basic passive circuit element.
- A generalized voltage controlled memristor:

$$i = G(z, u)u, \quad \frac{dz}{dt} = f(z, u),$$

where $z \in \mathbb{R}^n$ is the vector of internal state variables and G(z, u) is called the memductance.

The parallel inductor-capacitor-memristor circuit

• The parallel inductor-capacitor-memristor circuit: two linear elements (*C* and *L*, the inductor series resistance is represented as *r*₀) and a nonlinear active voltage controlled memristor defined by

$$i_M = \alpha u_M z, \quad \dot{z} = -\beta + u_M^2.$$

- Circuit equations: $L\dot{x} = y - r_0 x,$ $C\dot{y} = -x - \alpha yz$ $\dot{z} = -\beta + y^2,$ where $x = i_L$ and $y = u_C$.
- Parameter values: L = 0.025, C = 0.025, $\alpha = 0.825$, $\beta = 10$, r_0 is a bifurcation parameter.

Example trajectory of the circuit

• Parameter values: L = 0.025, C = 0.025, $\alpha = 0.825$, $\beta = 10$, $r_0 = 1$.



• When $\beta > 0$, $\alpha \neq 0$, $r_0 \neq 0$ the dynamical system has two equilibrium points $(x, y, z) = (\pm \sqrt{\beta}r_0^{-1}, \pm \sqrt{\beta}, -\alpha^{-1}r_0^{-1}) \approx (\pm 3.1623, \pm 3.1623, -1.2121).$

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Return map

- Equilibria $(x, y, z) = (\pm \sqrt{\beta} r_0^{-1}, \pm \sqrt{\beta}, -\alpha^{-1} r_0^{-1}), \sqrt{\beta} = \sqrt{10} \approx 3.16227766.$
- To reduce the continuous problem to the discrete one we use the method of the return map (Poincaré map).

•
$$\Sigma = \Sigma_1 \cup \Sigma_2$$
 — union of half-planes,
 $\Sigma_1 = \{ w = (x, y, z) : y = +3.16227766, \dot{y} < 0 \},$
 $\Sigma_2 = \{ w = (x, y, z) : y = -3.16227766, \dot{y} > 0 \}.$

• The return map $P \colon \Sigma \mapsto \Sigma$

$$P(x) = \varphi(\tau(x), x),$$

 $\varphi(t, x)$ is the trajectory with the initial point x, and $\tau(x) > 0$ is the time needed for the trajectory to reach Σ .

Bifurcation diagram for the return map P

- 2001 equidistant values in the interval $r_0 \in [0.5, 1.5]$,
- 500 iterations skipped, 5000 iterations plotted,
- initial point (x, y, z) = (-0.1, -0.1, 0.1) for $r_0 = 0.5$,
- continuation method: endpoint of the trajectory is used as an initial point for the next parameter value,
- results obtained for $r_0 \in [0.86, 1.22]$:



- For nonlinear systems there may exist multiple attractors.
- Finding multiple attractors
 - For fixed parameter values we find steady states for 1001 × 501 initial points filling uniformly the rectangle
 (x₀, y₀, z₀) ∈ [-10, 10] × [3.16227766] × [-5, 5] ⊂ Σ₁.
 - In each case a new attractor is found, we verify whether it belongs to an existing bifurcation plot.
 - If not, a new bifurcation plot containing this attractor is constructed using the continuation method.
- Computations are carried out for 151 equidistant parameter values in the range $r_0 \in [0.5, 2.0]$.
- Ten disconnected bifurcation plots have been found.

A complete bifurcation diagram $r_0 \in [0.5, 2.0]$

- Ten disconnected bifurcation plots have been found.
- Some regions are very narrow very fine sampling of the parameter space is necessary to find attractors.



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Regions of coexisting attractors



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The number of attractors found versus r_0

• The total number of attractors and the number of chaotic attractors found versus *r*₀.



- The maximum number of six (periodic) attractors is observed for $r_0 = 1.23$.
- Four chaotic attractors are observed for $r_0 = 1.0307$.
- Five chaotic attractors are observed for $r_0 = 1.030689$.

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Chaotic attractors existing for $r_0 = 1.0307$

- Four attractors are observed for $r_0 = 1.0307$.
- One of the attractors (red) occupies a large part of the state space,
- Three attractors are located very close to each other (blue, green and magenta).



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Attractors, variable ranges: $y \in [-10, 10]$, $z \in [-15, 15]$



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Attractors, $y \in [-10, 10]$, $z \in [-15, 15]$, cont.



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Attractors, $y \in [-10, 10]$, $z \in [-15, 15]$, cont.



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Basins of attraction

- For a given attractor A its basin of attraction B(A) is defined as a set of initial points such that if a trajectory is started in B(A) then it converges to A.
- Search of basins of attraction for the plane $\Sigma_3 = \{w = (x, y, z) : y = 3.16227766\}.$
- We find steady states for 2001 × 1001 initial points filling uniformly the rectangle
 R = (x₀, y₀, z₀) ∈ [-10, 10] × [3.16227766] × [-5, 5] ⊂ Σ₃.
- Initial points are plotted with colors corresponding to the steady state obtained.
- Attractors are plotted in black: for periodic attractors we use the \times symbol and for chaotic attractors we use dots.

Basins of attraction ($x \in [-10, 10]$, $z \in [-5, 5]$)



Basins of attraction ($x \in [-10, 10]$, $z \in [-5, 5]$), cont.



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Basins of attraction ($x \in [-10, 10]$, $z \in [-5, 5]$), cont.



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Basins of attraction for $r_0 = 1.0307$ and $r_0 = 1.030689$

- variable ranges: $x \in [2.29, 2.36]$, $z \in [-1.57, -1.51]$.
- four chaotic attractors for $r_0 = 1.0307$,

 $r_0 = 1.0307$

• five chaotic attractors for $r_0 = 1.030689$.



 $r_0 = 1.030689$

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- Due to rounding errors results obtained by numerical simulations of nonlinear systems may be unreliable.
- Rounding errors accumulate and are propagated in further computations.
- For more complex problems this may result in totally wrong answers.
- Interval arithmetic based computations may be used to obtain rigorous results.
 - The vector field is integrated using the rigorous Taylor integration method of order 30 with automatic time step control.
 - For the evaluation of the return map *P* and its Jacobian the CAPD library is used.

How to prove the existence of an attractor

- A general technique: construct a trapping region.
 - $\Omega \subset \Sigma$ such that $P(\Omega) \subset P$ is called a *trapping region*.
 - To prove that P(Ω) ⊂ P cover Ω by interval vectors w_k, find enclosure u_k ⊃ P(w_k) and verify that u_k ⊂ Ω.
 - Each bounded trapping region contains at least one attractor.
 - The existence of non-overlapping trapping regions implies the existence of multiple attractors.

• For periodic attractors use the interval Newton method.

- The interval Newton operator for the map F: N(x) = x̂ − F'(x)⁻¹F(x̂), where x̂ ∈ x and F'(x) is an interval matrix containing the Jacobian matrices F'(x) for x ∈ x.
- if $N(\mathbf{x}) \subset \mathbf{x}$, then \mathbf{x} contains exactly one zero of f.
- To prove the existence of period-*p* orbits of *P* apply the interval Newton method to the map $F = (F_0, F_1, \ldots, F_{p-1})$ defined by: $F_k(w_0, w_1, \ldots, w_{p-1}) = w_{(k+1) \mod p} P(w_k)$, for $k = 0, 1, \ldots, p-1$.

The existence of periodic attractors

- The existence of all 353 periodic attractors reported in the figure with the number of attractors is proved.
- Example: 6 periodic attractors for $r_0 = 1.23$:
 - p the period of the orbit of P,
 - *T* the flow time (the period of the continuous time system),
 - bounds for (x_0, y_0, z_0) .

n	р	Т	(x_0, y_0, z_0)
1,2	1	0.326146935489_{17}^{28}	$(\pm 1.35418887855_{75}^{96}, \pm 3.16227766,$
			$-1.93533813181_{55}^{76})$
3,4	2	0.4304783060_3^4	$(\pm 1.7004761963_{67}^{70}, \pm 3.16227766,$
		-	-1.41582847815_{53}^{74})
5,6	3	1.40924841_{69}^{71}	$(\pm 1.1050156992^{82}_{79}, \pm 3.16227766,$
			$-2.462173856270_{77}^{96}$)

Two chaotic attractors for $r_0 = 0.99$

- (a) the trapping region Ω (red) for the return map *P* enclosing a numerically observed trajectory (black), the existence of the symmetric attractor follows from the symmetry of the vector field.
- (b) sets Q_1 , Q_2 , Q_3 with complex symbolic dynamics (implies positive topological entropy, the infinite number of periodic orbits and the topological chaos).



Chaotic attractors for $r_0 = 1.0307$

- Four chaotic attractors are observed in simulations: one wide self-symmetric attractor and three tiny attractors (one self-symmetric and a symmetric pair).
- (a) The trapping region Ω_0 (light red), its image (black), and three attractors (blue, green, magenta).
- (b) The three trapping regions Ω_1 , Ω_2 , $\Omega_3 \cup \Omega_4 \cup \Omega_5$.



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Conclusions

- Dynamical phenomena in the parallel inductor-capacitor-memristor circuit studied numerically.
- A systematic search for coexisting attractors carried out.
- The existence of multiple attractors has been observed and bifurcation diagrams have been constructed.
- Basins of attraction have been computed.
- The coexistence of attractors has been proved using interval analysis tools.
 - The existence of periodic attractors is confirmed by applying the interval Newton method to prove the existence of stable periodic orbits of an associated return map.
 - For numerically observed chaotic attractors the existence of attractors is proved by constructing trapping regions enclosing chaotic trajectories of the return map.
 - The existence of topological chaos is proved using the method of covering relations.

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